



SCH1436 — N-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- ON-resistance $R_{DS(on)1}=135m\Omega$ (typ.)
- 4V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		30	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		1.8	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	7.2	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.8	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

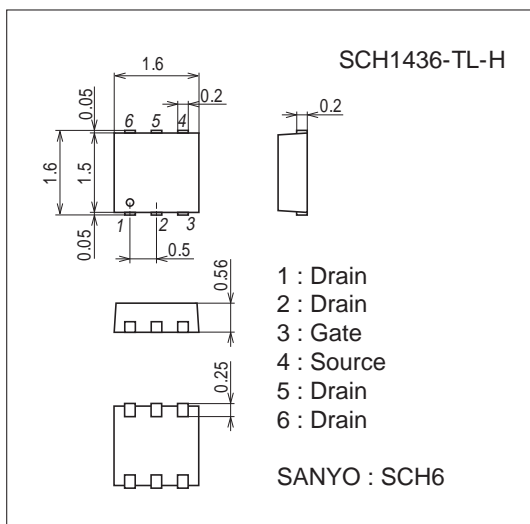
This product is designed to "ESD immunity < 200V**", so please take care when handling.

* Machine Model

Package Dimensions

unit : mm (typ)

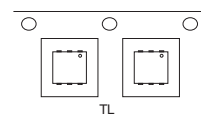
7028-002



Product & Package Information

- Package : SCH6
- JEITA, JEDEC : SOT-563
- Minimum Packing Quantity : 5,000 pcs./reel

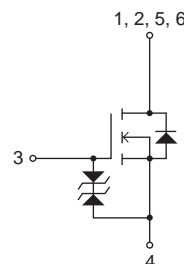
Packing Type : TL



Marking



Electrical Connection

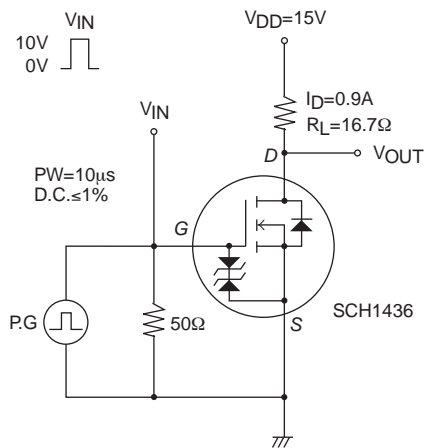


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Electrical Characteristics at Ta=25°C

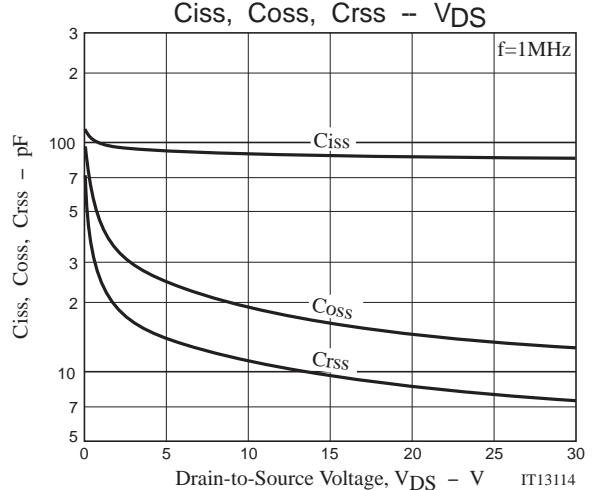
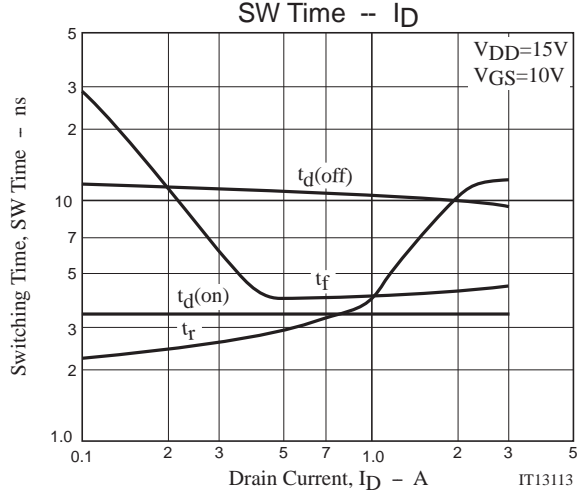
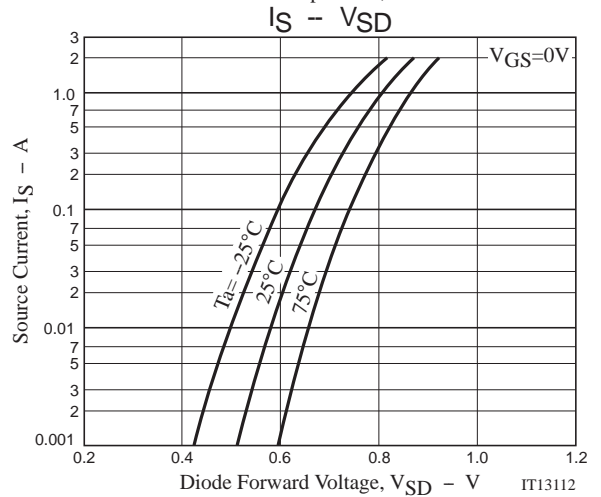
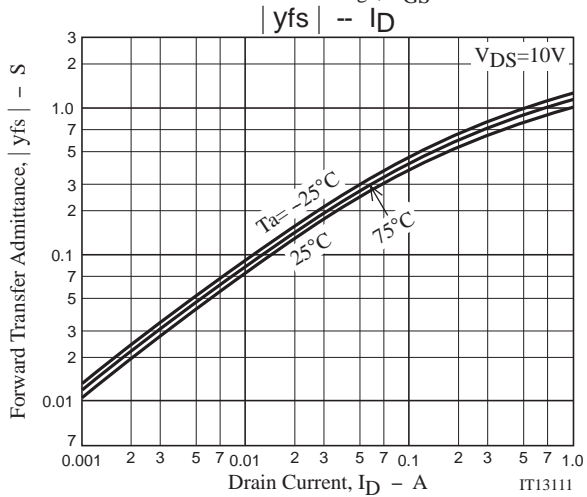
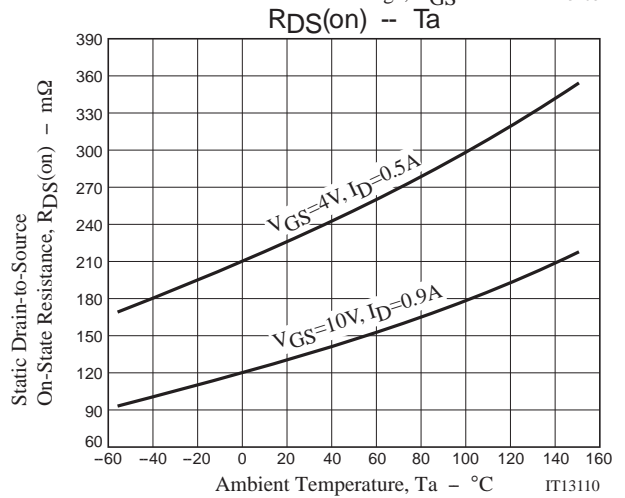
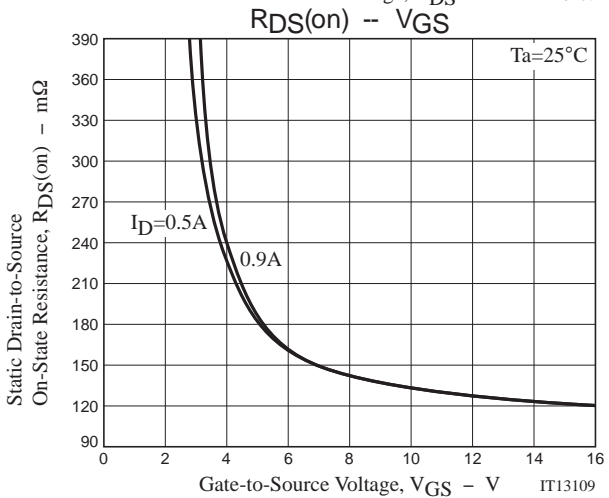
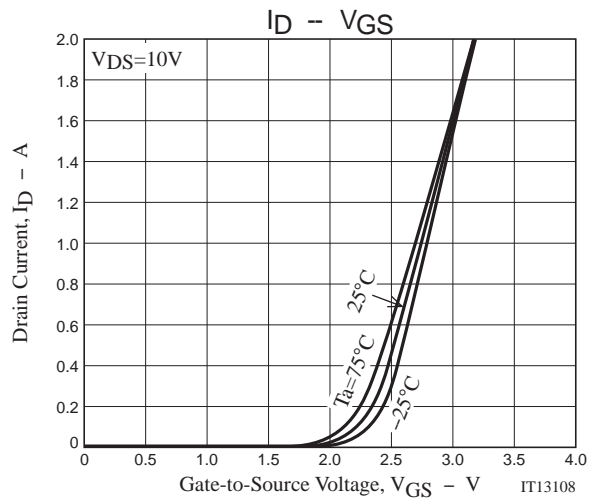
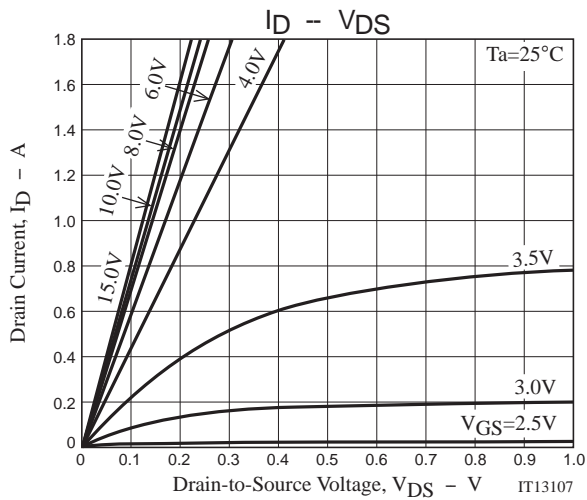
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	VDS=10V, ID=0.9A		1.1		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=0.9A, VGS=10V		135	180	mΩ
	RDS(on)2	ID=0.5A, VGS=4V		230	330	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		88		pF
Output Capacitance	Coss			19		pF
Reverse Transfer Capacitance	Crss			11		pF
Turn-ON Delay Time	td(on)			3.4		ns
Rise Time	tr	See specified Test Circuit.		4.0		ns
Turn-OFF Delay Time	td(off)			10.4		ns
Fall Time	tf			4.2		ns
Total Gate Charge	Qg			2.0		nC
Gate-to-Source Charge	Qgs	VDS=10V, VGS=10V, ID=1.8A		0.33		nC
Gate-to-Drain "Miller" Charge	Qgd			0.29		nC
Diode Forward Voltage	VSD		IS=1.8A, VGS=0V		0.86	1.2

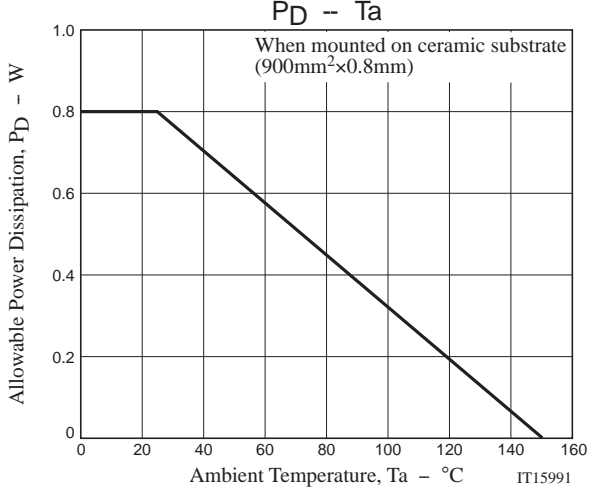
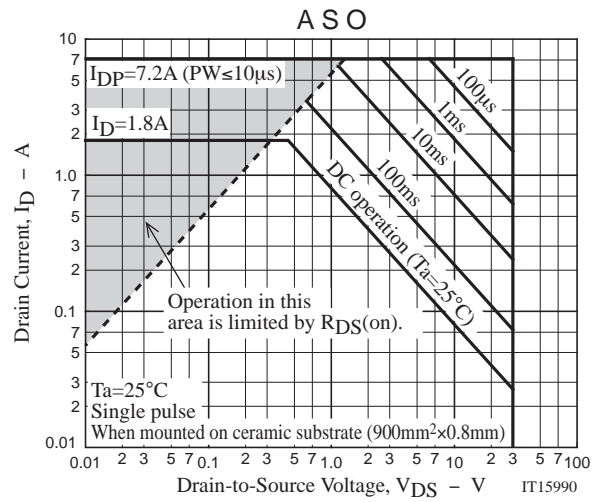
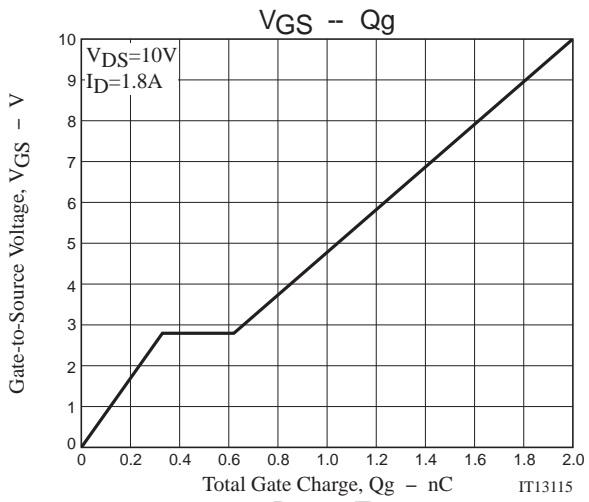
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
SCH1436-TL-H	SCH6	5,000pcs./reel	Pb Free and Halogen Free





SCH1436

Taping Specification

SCH1436-TL-H

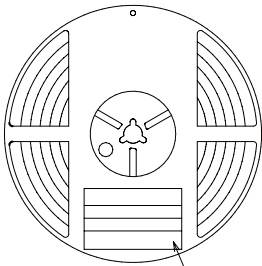
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
SCH6	SCH6	5,000	25,000	150,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit: mm)

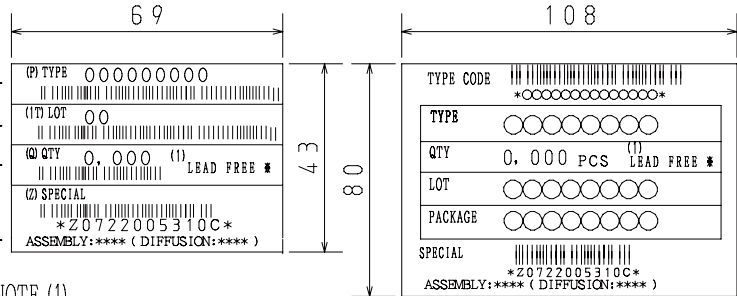
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Type No. →
LOT No. →
Quantity →
Origin →

Reel label



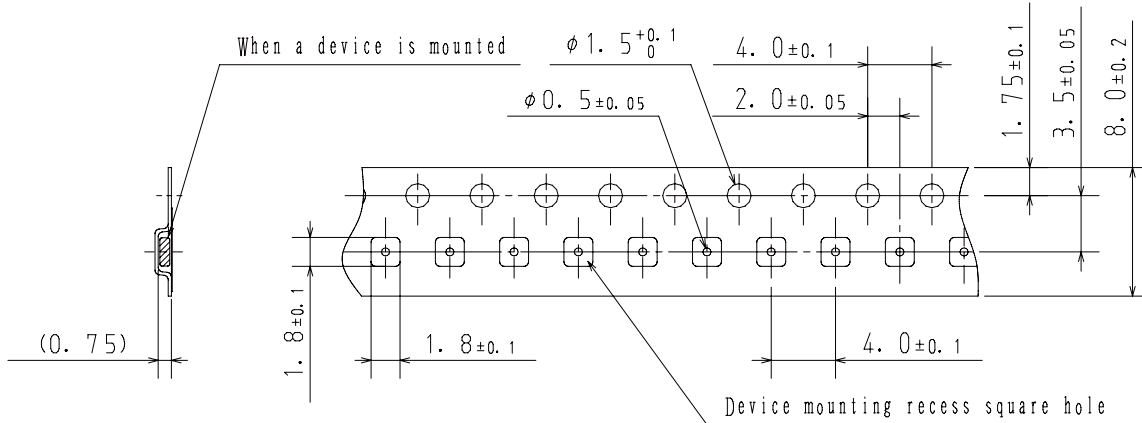
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

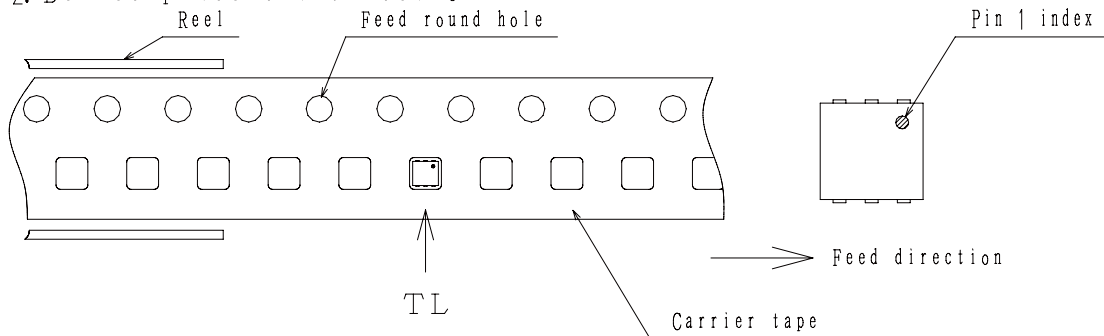
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



Those with pin 1 index on the feed hole side.....TL

Note on usage : Since the SCH1436 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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